TOSHIBA 300EXH22

TOSHIBA FAST RECOVERY DIODE SILICON DIFFUSED TYPE

300EXH22

HIGH SPEED RECTIFIER APPLICATIONS

Unit in mm

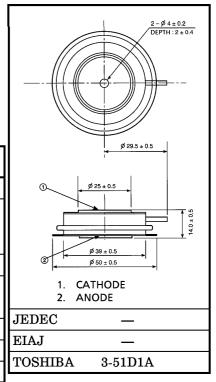
Repetitive Peak Reverse Voltage $: V_{RRM} = 2500V$

Average Forward Current $: I_{F(AV)} = 300A$

: $t_{rr} = 5 \mu s (MAX.) (T_j = 25 ^{\circ}C)$ Reverse Recovery Time

MAXIMUM RATINGS

CHARACTERISTIC	SYMBOL	RATING	UNIT	
Repetitive Peak Reverse Voltage	v_{RRM}	2500	V	
Non-Repetitive Peak Reverse Voltage (Non-Repetitive ≤ 5 ms, $T_j = 0 \sim 125$ °C)	V _{RSM}	2600	V	
Average Forward Current	I _{F (AV)}	300	Α	
Peak One Cycle Surge Forward	Incre	6000 (50Hz)	Α	
Current	IFSM	6600 (60Hz)	_ ^	
Junction Temperature Range	T_{j}	-40~125	$^{\circ}\mathrm{C}$	
Storage Temperature Range	$\mathrm{T_{stg}}$	-40~125	$^{\circ}\mathrm{C}$	
Mounting Force	_	10.8±1.0	kN	



ELECTRICAL CHARACTERISTICS

CHARACTERISTIC	SYMBOL	TEST CONDITION		MIN.	MAX.	UNIT
Repetitive Peak Reverse Current	I_{RRM}	$V_{ m RRM} = 2500 m V, \ T_j = 125 m ^{\circ} C$			50	mA
Peak Forward Voltage	$ m v_{RM}$	$I_{FM} = 1000A, T_j = 25^{\circ}C$		I	1.75	V
Reverse Recovery Time	t _{rr}	$I_{ m F}$ =300A $di_{ m F}/dt$ =50A/ μ s	$T_j = 25$ °C	l	5.0	449
			$T_j = 125$ °C	l	7.0	μ s
Thermal Resistance (Junction to Fin)	R _{th (j-f)}	DC		1	0.05	°C/W

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